

Features: (typical values)

- Low Distortion
- High Second Order IP2 +65.0 dBm.
- High Third Order IP3 +42.0 dBm.
- High Gain..... +50 dB.

Maximum Ratings

Storage Temperature	-55°C to +125°C
DC Voltage	+17 volts
RF Input Power	+15.0 dBm.
Case Temperature	+95°C

Specifications (Referenced to 50 ohms)

Parameter	Typical Conditions	Min Value	Max Value	Units
Frequency		1000	2000	MHz.
Gain	50	47	53	dB.
Gain Flatness	±0.3		±1.0	dB.
Gain Var. over temp.	0.5			ΔdB.
Pout @ 1dB Comp	+30	+28		dBm.
Noise Figure	3.5		4.0	dB.
Reverse Isolation	57			dB.
IP ₃ /IP ₂ (two tone)*	42/65			dBm.
HIP2 (2 nd harm.)	75			dBm.
VSWR In/Out	1.4:1		2.0:1	Ratio
Supply Required	+15/1600		+15V/1600	v/mA

Min. and max. values are from 0°C to +85°C

*IP3 and IP2 are in band output intercept points



